

Schottky Barrier Rectifiers

Reverse Voltage 20 to 200V Forward Current 1.0A

(Pb) Lead(Pb)-Free

FEATURES

- * Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- * Low power loss,high efficiency
- * For use in low voltage high frequency inverters, free wheeling,and polarity protection applications
- * Guardring for over voltage protection
- * High temperature soldering guaranteed: 260°C/10 seconds at terminals

Mechanical Data

Case: SOD-323HE

molded plastic over sky die

Terminals: Tin Plated, solderable per

MIL-STD-750, Method 2026

Polarity: Color band denotes cathode end

Mounting Position: Any

Weight: 0.011 g

Handling precautin:None

1.Electrical Characteristic

Maximum & Thermal Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

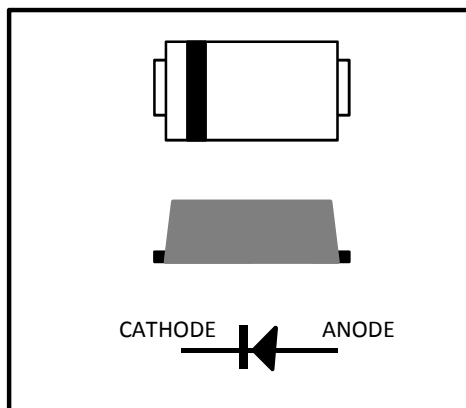
Parameter Symbol	symbol	B120E	B130E	B140E	B150E	B160E	B180E	B1100E	B1150E	B1200E	Unit
device marking code		12	13	14	15	16	18	110	115	120	
Maximum repetitive peak reverse voltage	V_{RRM}	20	30	40	50	60	80	100	150	200	V
Maximum RMS voltage	V_{RMS}	14	21	28	35	42	56	70	105	140	V
Maximum DC blocking voltage	V_{DC}	20	30	40	50	60	80	100	150	200	V
Maximum average forward rectified current at $T_c = 75^\circ\text{C}$	$I_{F(AV)}$	1.0									A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	22									A
Typical thermal resistance (Note 1)	$R_{\theta A}$ $R_{\theta L}$	220 50									°C/W
Operating junction temperature range	T_J	-55 to +125									°C
storage temperature range	T_{STG}	-55 to +150									°C

Electrical Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

Parameter Symbol	symbol	B120E	B130E	B140E	B150E	B160E	B180E	B1100E	B1150E	B1200E	Unit
Maximum instantaneous forward voltage at(IF = 0.7 A, T _J = 25°C) (IF = 1.0 A, T _J = 25°C)	V _F	0.48 0.55			0.7		0.85		0.9	0.92	V
Maximum DC reverse current at rated DC blocking voltage T _A = 25°C T _J = 125°C	I _R	0.25 10	0.13 10	0.03 10							mA
Typical junction capacitance at 4.0V, 1MHz	C _J	160									PF

NOTES:

1. 8.0mm² (.013mm thick) land areas



We declare that the material of product is
Halogen free (green epoxy compound)

2. Ratings and Characteristic Curves ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Fig. 1 Forward Current Derating Curve

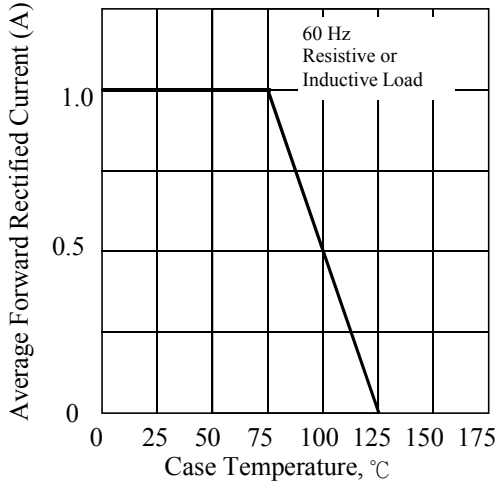


Fig. 2 Maximum Non-repetitive Peak Forward Surge Current

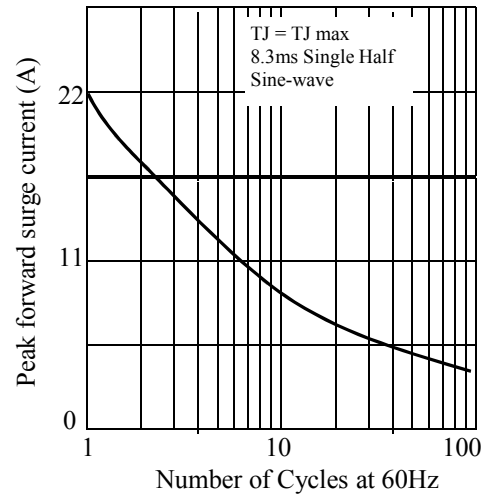


Fig 3. Typical Instantaneous Forward Characteristics

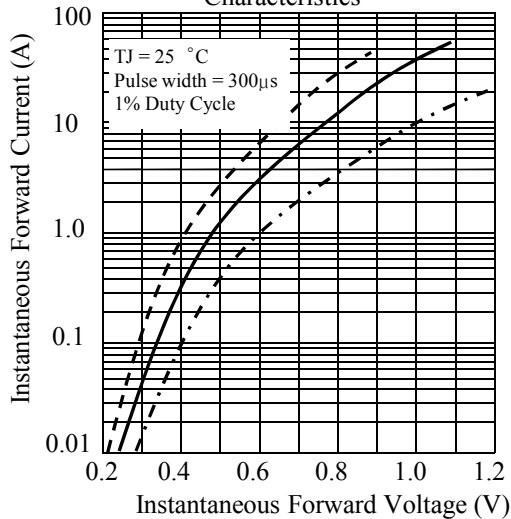


Fig 4. Typical Reverse Characteristics

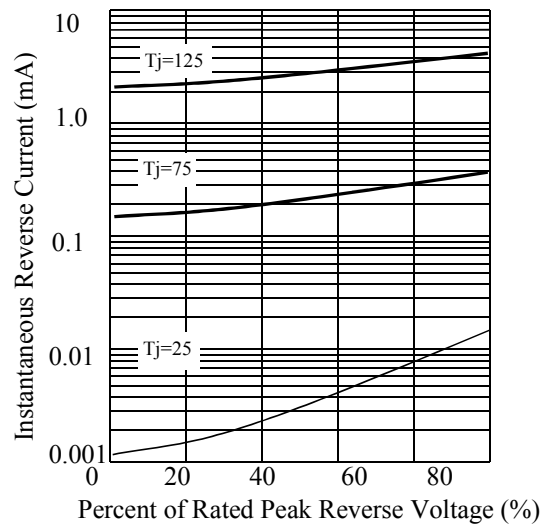


Fig 5. typical transient thermal impedance

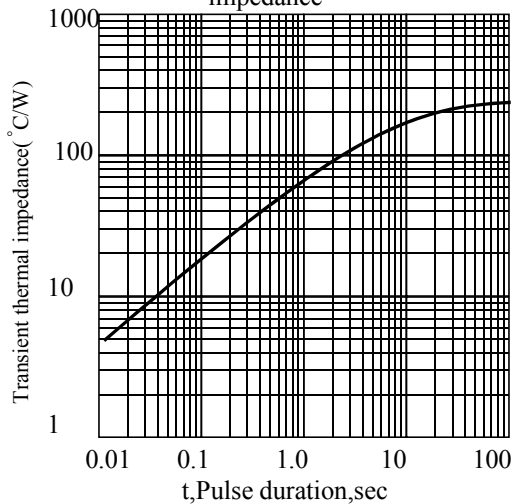
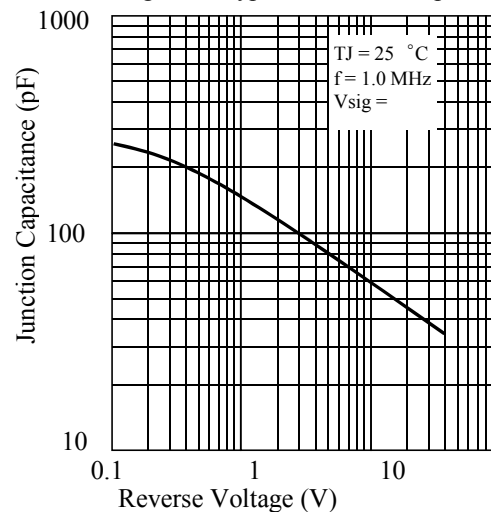
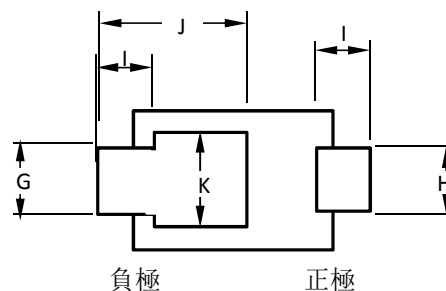
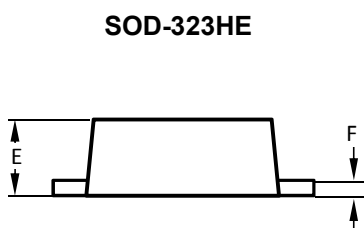
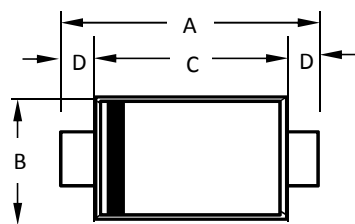


Fig 6. Typical Junction Capacitance

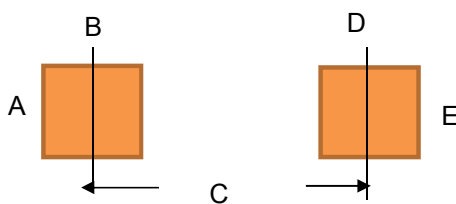


3. dimension:



DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.30	2.70	0.091	0.106
B	1.20	1.35	0.047	0.053
C	1.75	1.95	0.069	0.077
D	0.30Typ		0.012Typ	
E	0.55	0.75	0.022	0.030
F	0.10	0.20	0.004	0.008
G	0.50	0.55	0.020	0.022
H	0.50	0.55	0.020	0.022
I	0.40	0.60	0.016	0.024
J	1.15	1.55	0.045	0.061
K	0.8Typ		0.032Typ	

Suggested solder pad layout

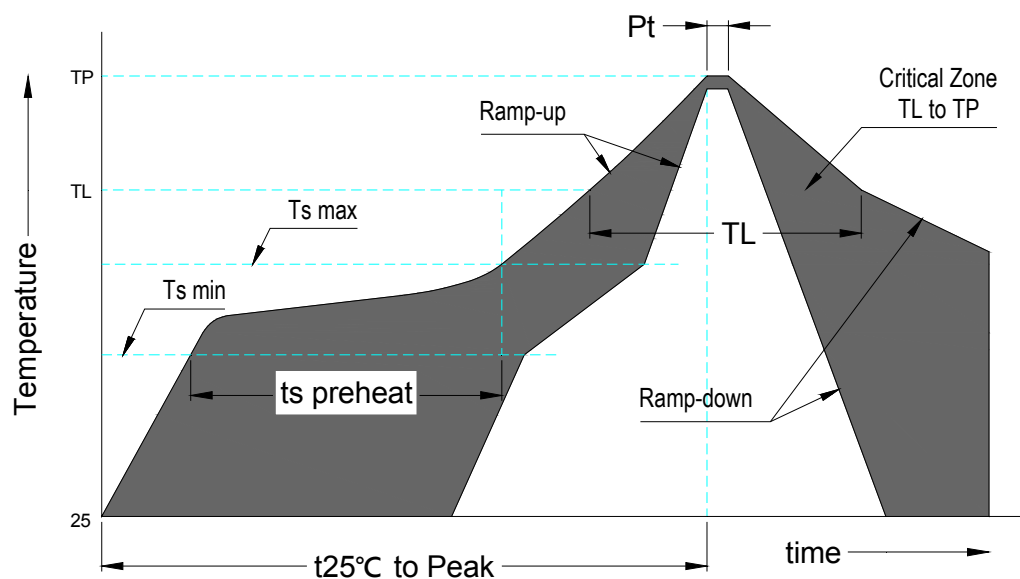


Dimensions in inches and (millimeters)

PACKAGE	A	B	C	D	E
SOD-323HE	0.032(0.8)	0.032(0.8)	0.085(2.15)	0.032(0.8)	0.032(0.8)

5. Suggested thermal profile for soldering process

1. Storage environment Temperature=5~40 °C Humidity=55±25%
2. Reflow soldering of surface-mount device



3. Reflow soldering

Profile Feature	Soldering Condition
Average ramp-up rate(T_L to T_P)	<3°C/sec
Preheat	
- Temperature Min(T_{smin})	150°C
- Temperature Max(T_{smax})	200°C
- Time(min to max)(t_s)	60~120sec
T_{smax} to T_L	
- Ramp-up Rate	<3sec
Time maintained above:	
- Temperature (T_L)	217°C
- Time(t_L)	60-260sec
Peak Temperature(T_P)	255 -0/+5°C
Time within 5°C of actual Peak Temperature(T_P)	10~30sec
Ramp-down Rate	<6°C/sec
Time 25°C to Peak Temperature	<6minutes

6.High reliability test capabilities

Item Test	Condition	Reference
Solder Resistance	at 260±5°C for 10±2sec immerse	MIL-STD-750D METHOD-2031
Solderability	at 245±5°C for 5 sec	MIL-STD-202F METHOD-208
High Temperature Reverse Bias	V _R =80% rate at T _j =125°C for 168hrs	MIL-STD-750D METHOD-1038
Forward Operation Life	Rated average rectifier current	MIL-STD-750D METHOD-1027
Intermittent Operation Life	T _A =25°C, I _F =I _O	MIL-STD-750D METHOD-1036
Pressure Cooker	15P _{SIG} at T _A =121°C for 4hrs	JESD22-A102
Temperature Cycling	-55°C to +125°C dwelled for 30 min. and transferred for 5min. Total 10 cycles	MIL-STD-750D METHOD-1051
Thermal Shock	0°C for 5min. Rise to 100°C for 5min. Total 10 cycles	MIL-STD-750D METHOD-1056
Forward Surge	8.3ms single half sine-wave superimposed on rated load,one surge	MIL-STD-750D METHOD-4066-2
Humidity	at T _A =85°C, R _H =85% for 1000hrs	MIL-STD-750D METHOD-1021
High Temperature Storage Life	at 150°C for 1000hrs	MIL-STD-750D METHOD-1031